



Vincotech

**B0-SP10NAD600S704-PE19F18T
B0-SP10NAE600S704-PE29F18T**
datasheet

flowANPC S3 split		950 V / 600 A
Topology features		
<ul style="list-style-type: none">• Temperature sensor• Advanced Neutral Point Clamped topology• Integrated Capacitor• Split topology		
Component features		flow S3 12 mm housing
<ul style="list-style-type: none">• Low collector emitter saturation voltage• High speed and smooth switching		
Housing features		PE19F18T PE29F18T
<ul style="list-style-type: none">• Base isolation: AlN• CT1600 housing material• Compact, baseplate-less housing• VINcoPress Technology• Thermo-mechanical push-and-pull force relief• Press-fit pin• Reliable cold welding connection		
Extra features		Schematic
<ul style="list-style-type: none">• Heat-Pipe and Heat-Sink optimized layout• PCB layout optimized pinout		
Target applications		PE19F18T PE29F18T
<ul style="list-style-type: none">• Energy Storage Systems• Solar Inverters		
Types		
<ul style="list-style-type: none">• B0-SP10NAD600S704-PE19F18T• B0-SP10NAE600S704-PE29F18T		



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**B0-SP10NAD600S704-PE19F18T
B0-SP10NAE600S704-PE29F18T**
datasheet

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
AC Switch				
Collector-emitter voltage	V_{CES}		950	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	461	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	800	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	599	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

AC Diode

Peak repetitive reverse voltage	V_{RRM}		950	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	191	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	600	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	365	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Neutral Point Switch

Collector-emitter voltage	V_{CES}		950	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	282	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	800	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	539	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
DC-Link Diode				
Peak repetitive reverse voltage	V_{RRM}		950	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	191	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	600	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	365	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

DC-Link Switch

Collector-emitter voltage	V_{CES}		950	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	382	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	1200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	704	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Neutral Point Diode

Peak repetitive reverse voltage	V_{RRM}		1200	V	
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	171	A	
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	728	A	
Surge (non-repetitive) forward current	I_{FSM}	Single Half Sine Wave, $t_p = 10 \text{ ms}$	$T_j = 25^\circ\text{C}$	1040	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	$T_s = 80^\circ\text{C}$	431	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$	



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Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Capacitor (DC)				
Maximum DC voltage	V_{MAX}		750	V
		$T_j = 125 \text{ }^\circ\text{C}$	1000	
		$T_j = 150 \text{ }^\circ\text{C}$	750	
Operation Temperature	T_{op}		-55 ... 150	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...+($T_{\text{jmax}} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2 \text{ s}$	6000	V
Creepage distance			>12,7	mm
Clearance		B0-SP10NAD600S704-PE19F18T B0-SP10NAE600S704-PE29F18T	11,99 11,39	mm
Comparative Tracking Index	CTI		≥ 600	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	I_C [A]	T_j [°C]	Min	Typ	Max	

AC Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0065	25	4,15	4,85	5,65	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		400	25 125 150		1,21 1,23 1,24	1,4 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	950		25			8	µA
Gate-emitter leakage current	I_{GES}		20	0		25			200	nA
Internal gate resistance	r_g							0,75		Ω
Input capacitance	C_{res}	$f = 100$ kHz	0	25	25	25	49200	530	220	pF
Output capacitance	C_{oes}									
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g		±15		0	25		4100		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,16		K/W
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AC Diode

Static

Forward voltage	V_F				300	25 125 150	2,1	2,59 2,43 2,37	2,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 950$ V				25			12	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,26		K/W
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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Neutral Point Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0065	25	4,35	5,1	5,85	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		400	25 125 150		1,82 2,07 2,13	2,25 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	950		25			8	µA
Gate-emitter leakage current	I_{GES}		20	0		25			200	nA
Internal gate resistance	r_g							0,75		Ω
Input capacitance	C_{res}	$f = 100$ kHz	0	25	25	25	25200		pF	
Output capacitance	C_{oes}									
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g		±15		0	25		900		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,18		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	± 15	600	355	25		207,36		
Rise time	t_r					125		211,69		
						150		213,64		ns
Turn-off delay time	$t_{d(off)}$					25		36,11		
						125		38,61		
Fall time	t_f					150		39,6		ns
Turn-on energy (per pulse)	E_{on}	$Q_{fFWD}=1,08$ µC $Q_{rfFWD}=1,11$ µC $Q_{ffFWD}=1,12$ µC				25		176,43		
						125		210,44		
Turn-off energy (per pulse)	E_{off}					150		220,65		ns
						25		26,39		
						125		46,75		
						150		56,01		ns
						25		7,81		
						125		7,54		mWs
						150		7,55		
						25		12,45		
						125		17,92		mWs
						150		20,04		



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

DC-Link Diode

Static

Forward voltage	V_F				300	25 125 150	2,1	2,59 2,43 2,37	2,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_F = 950$ V			25			12	μA	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,26		K/W
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Dynamic

Peak recovery current	I_{RM}	$di/dt=6618$ A/μs $di/dt=5990$ A/μs $di/dt=6156$ A/μs	± 15	600	355	25		69,54		A
Reverse recovery time	t_{rr}					125		69,01		
Recovered charge	Q_r					150		68,97		
Recovered charge	Q_r		± 15	600	355	25		25,67		
Reverse recovered energy	E_{rec}					125		26,2		ns
Reverse recovered energy	E_{rec}					150		26,4		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25		1,08		μC
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					125		1,11		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					150		1,12		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25		0,411		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					125		0,425		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					150		0,431		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25		7251,59		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					125		7000,21		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					150		6801,22		A/μs



Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	

DC-Link Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,00975	25	4,35	5,1	5,85	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		600	25 125 150		1,82 2,07 2,13	2,25 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	950		25			12	µA
Gate-emitter leakage current	I_{GES}		20	0		25			300	nA
Internal gate resistance	r_g							0,5		Ω
Input capacitance	C_{res}	$f = 100$ kHz	0	25	25	25	37800	810	120	pF
Output capacitance	C_{oes}									
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g		±15		0	25		1350		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,14		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	±15	600	355	25		207,36		
Rise time	t_r					125		211,69		ns
						150		213,64		
Turn-off delay time	$t_{d(off)}$					25		36,11		
Fall time	t_f					125		38,61		ns
						150		39,6		
Turn-on energy (per pulse)	E_{on}					25		176,43		
Turn-off energy (per pulse)	E_{off}					125		210,44		ns
						150		220,65		
						25		26,39		
						125		46,75		ns
						150		56,01		
						25		7,81		
						125		7,54		mWs
						150		7,55		
						25		12,45		
						125		17,92		mWs
						150		20,04		



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max			

Neutral Point Diode

Static

Forward voltage	V_F				160	25 125 150		1,72 2,17 2,32	1,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_F = 1200$ V			25		280	1600	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,22		K/W
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Dynamic

Peak recovery current	I_{RM}	$di/dt=6618$ A/ μ s $di/dt=5990$ A/ μ s $di/dt=6156$ A/ μ s	± 15	600	355	25		69,54		
Reverse recovery time	t_{rr}					125		69,01		
Recovered charge	Q_r					150		68,97		
Reverse recovered energy	E_{rec}		± 15	600	355	25		25,67		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					125		26,2		
						150		26,4		
			± 15	600	355	25		0,395		
						125		0,43		
						150		0,469		μ C
			± 15	600	355	25		0,106		
						125		0,12		mWs
						150		0,14		
			± 15	600	355	25		7251,59		
						125		7000,21		
						150		6801,22		A/ μ s



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max			

Capacitor (DC)

Static

Capacitance	C	DC bias voltage = 0 V				25		750		V
Tolerance							-5		5	%
Dissipation factor		$f = 1$ kHz				25		0,1		%

Thermistor

Static

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P					25		130		mW
Power dissipation constant	d					25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %						3962		K
B-value	$B_{(25/100)}$	Tol. ±1 %						4000		K
Vincotech Thermistor Reference									I	

(1) Value at chip level

(2) Only valid with pre-applied Vincotech thermal interface material.



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AC Switch Characteristics

figure 1. IGBT

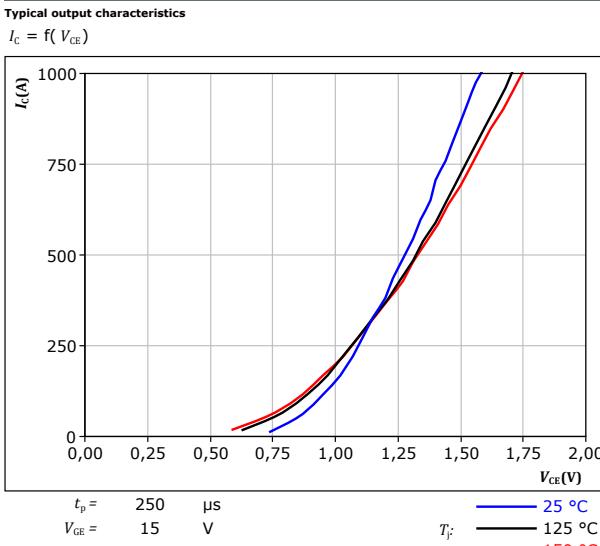


figure 2. IGBT

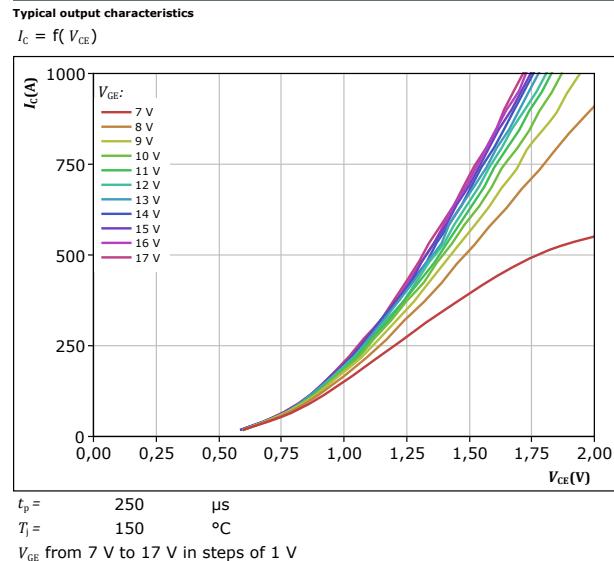


figure 3. IGBT

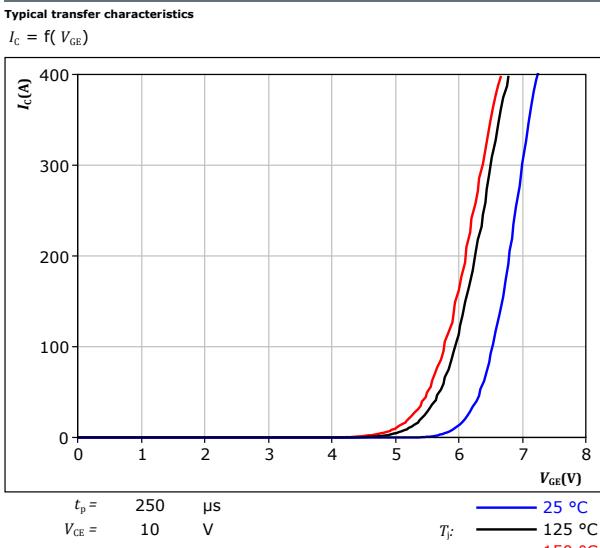
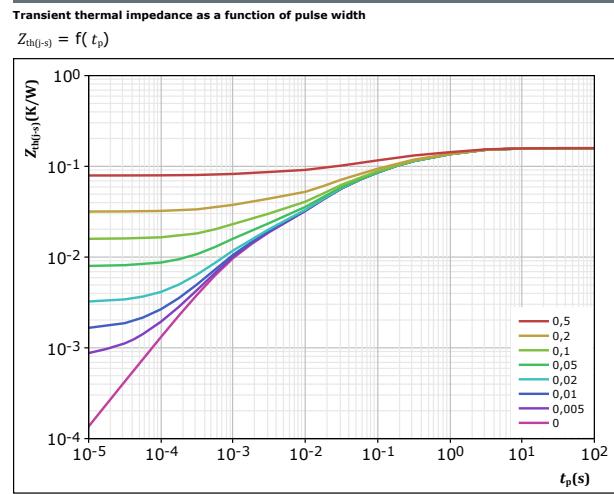


figure 4. IGBT



$D =$	t_p / T	R (K/W)	τ (s)
	0,158	9,88E-03	4,48E+00
		4,29E-02	9,18E-01
		5,31E-02	1,30E-01
		4,03E-02	2,06E-02
		1,24E-02	1,11E-03

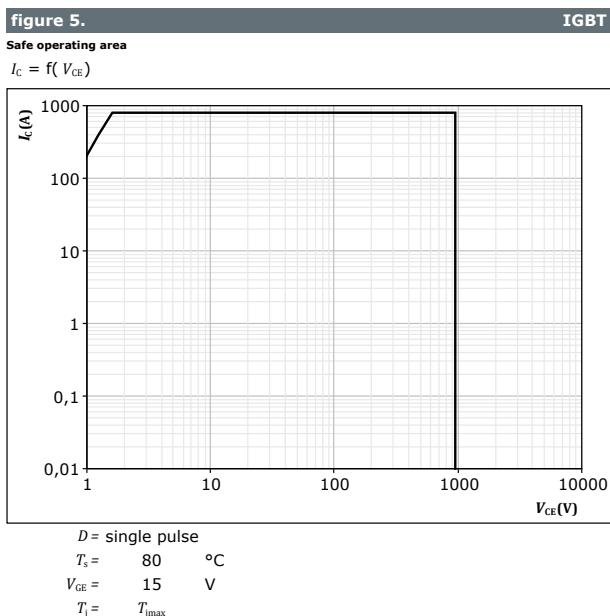
IGBT thermal model values



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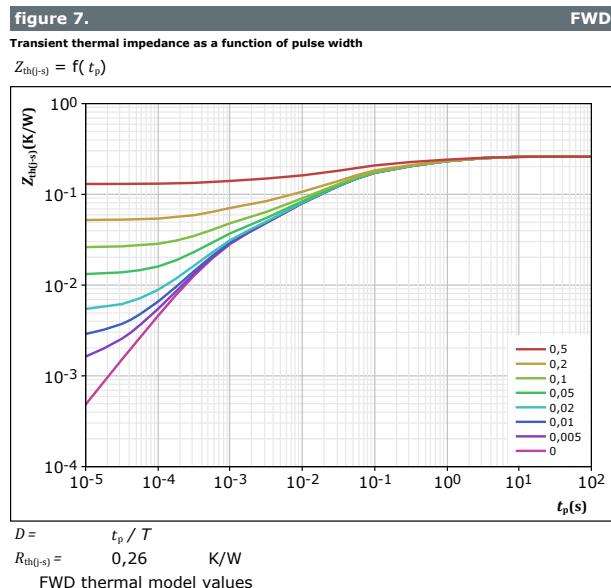
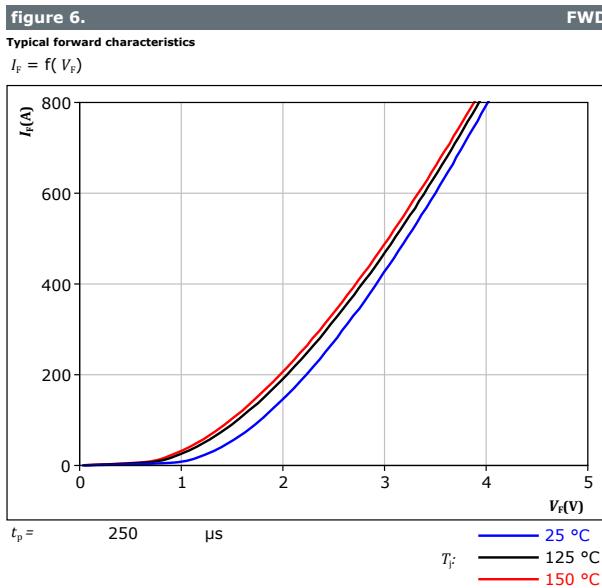




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AC Diode Characteristics





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Neutral Point Switch Characteristics

figure 8. IGBT

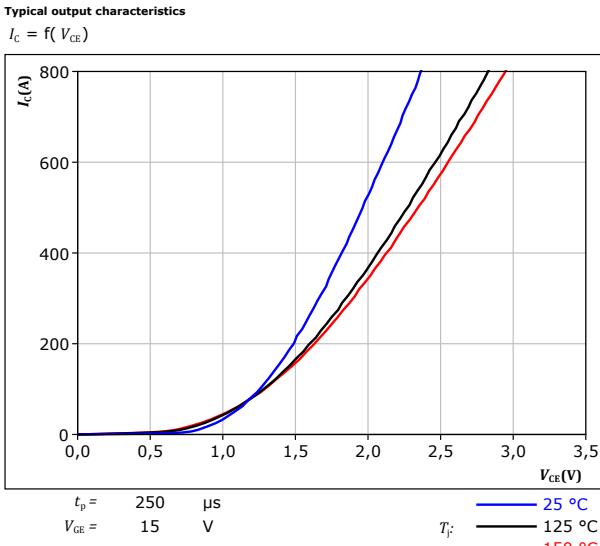


figure 9. IGBT

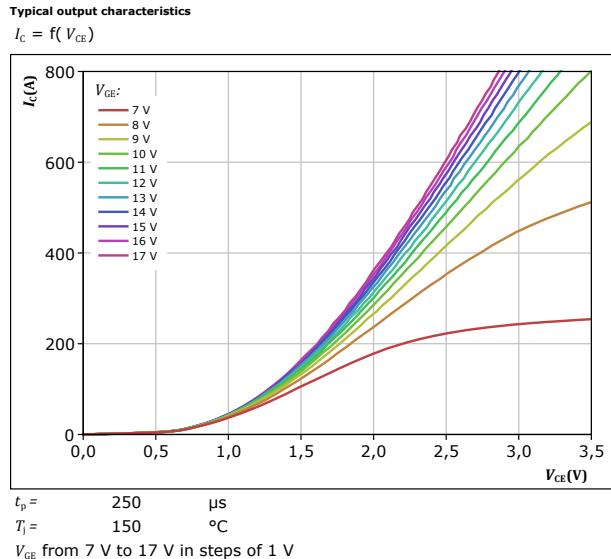


figure 10. IGBT

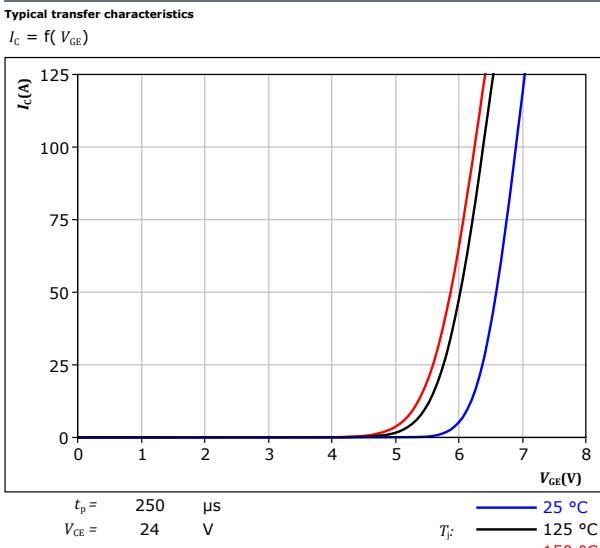
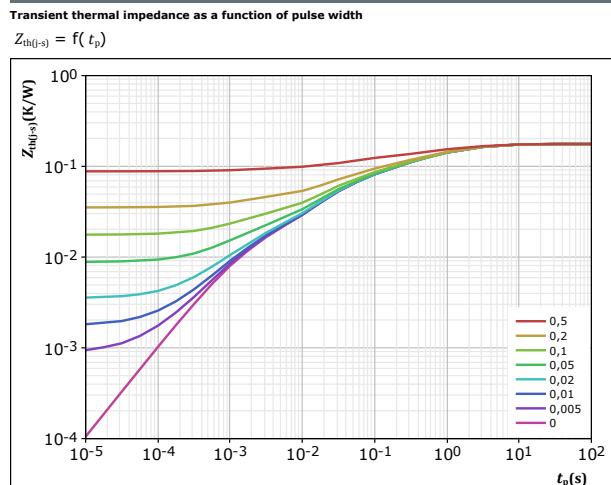


figure 11. IGBT

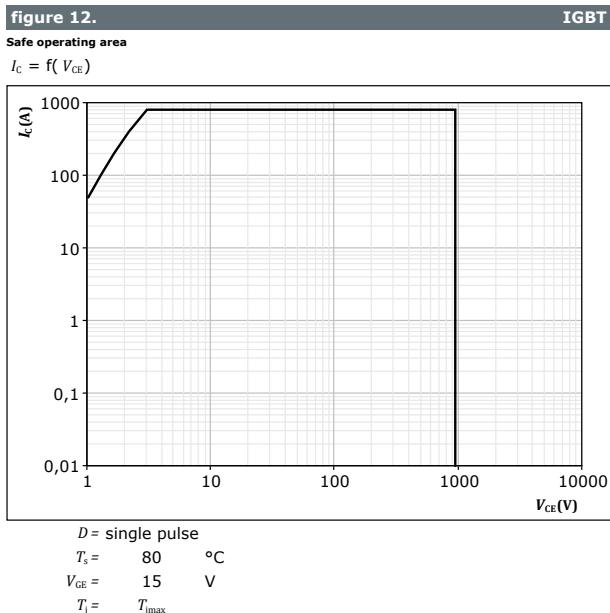




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Neutral Point Switch Characteristics





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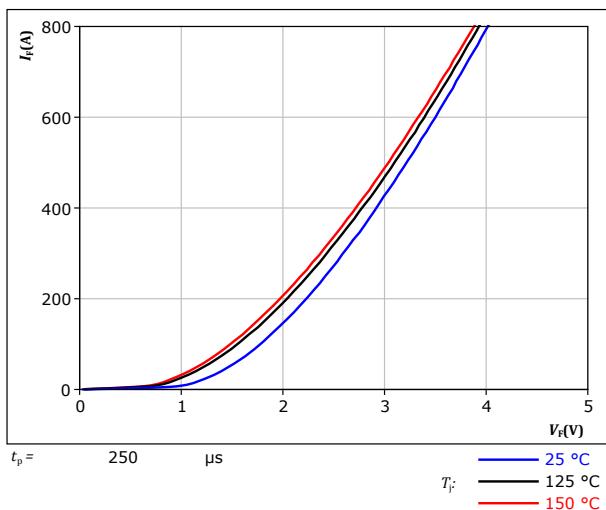
DC-Link Diode Characteristics

figure 13.

Typical forward characteristics

$$I_F = f(V_F)$$

FWD



$$t_p = 250 \mu\text{s}$$

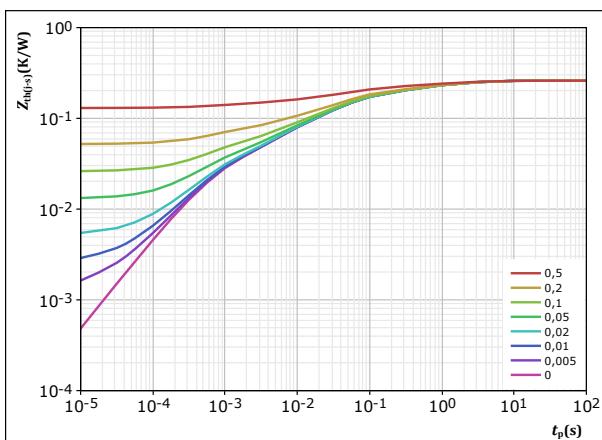
T_F :
— 25 °C
— 125 °C
— 150 °C

figure 14.

Transient thermal impedance as a function of pulse width

$$Z_{th(t-s)} = f(t_p)$$

FWD



$$D = \frac{t_p / T}{R_{th(t-s)}} = 0,26 \quad \text{K/W}$$

FWD thermal model values

R (K/W)	τ (s)
2,71E-02	2,94E+00
5,54E-02	5,40E-01
1,05E-01	5,17E-02
4,70E-02	7,63E-03
2,60E-02	6,45E-04



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DC-Link Switch Characteristics

figure 15. IGBT

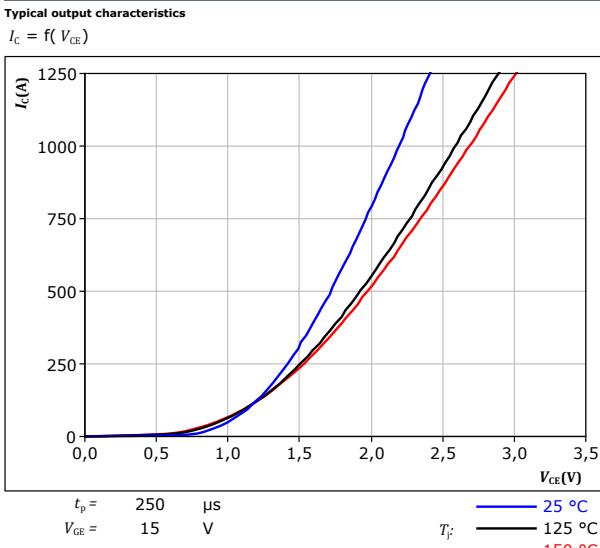


figure 16. IGBT

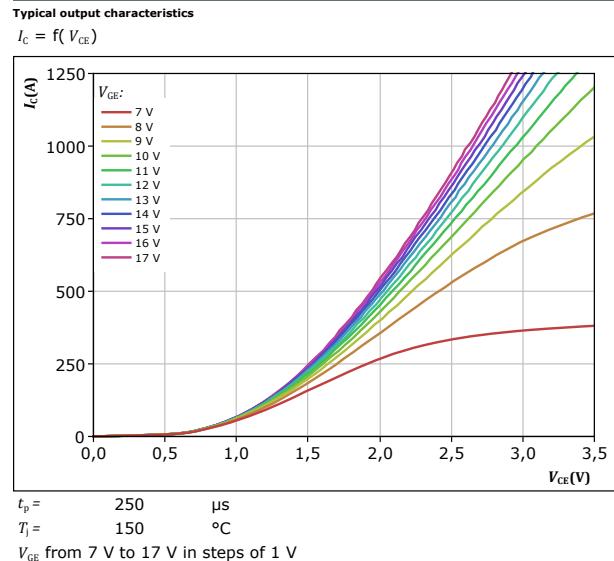


figure 17. IGBT

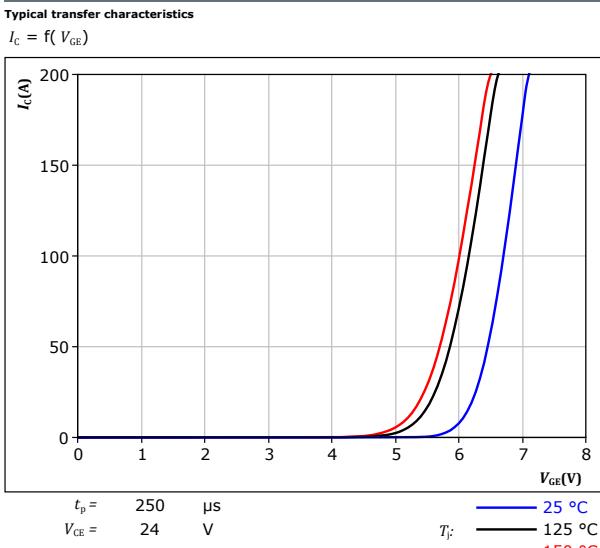
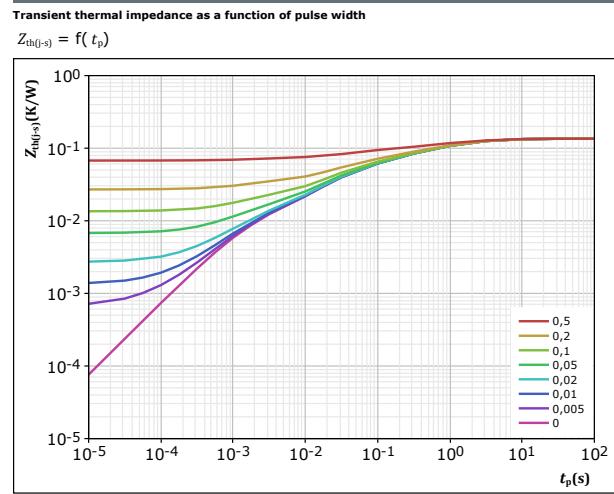


figure 18. IGBT

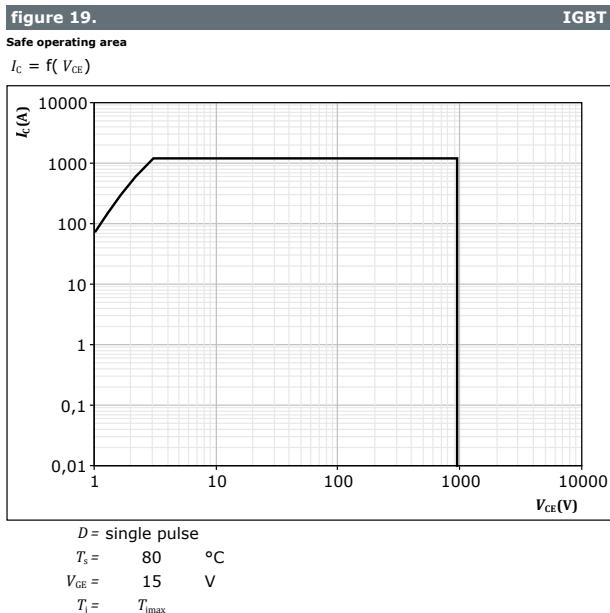




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datasheet

DC-Link Switch Characteristics

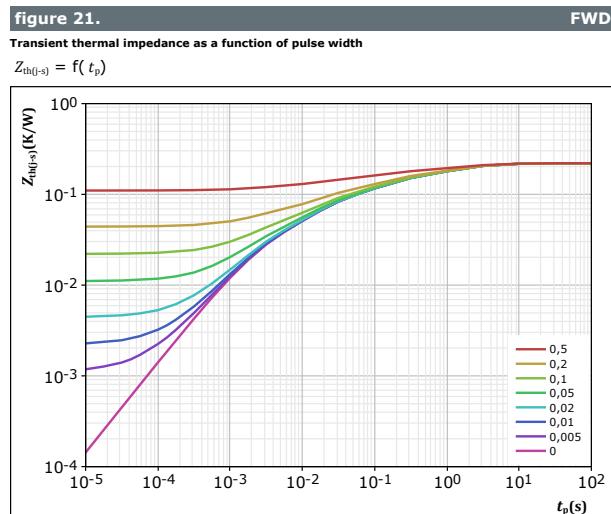
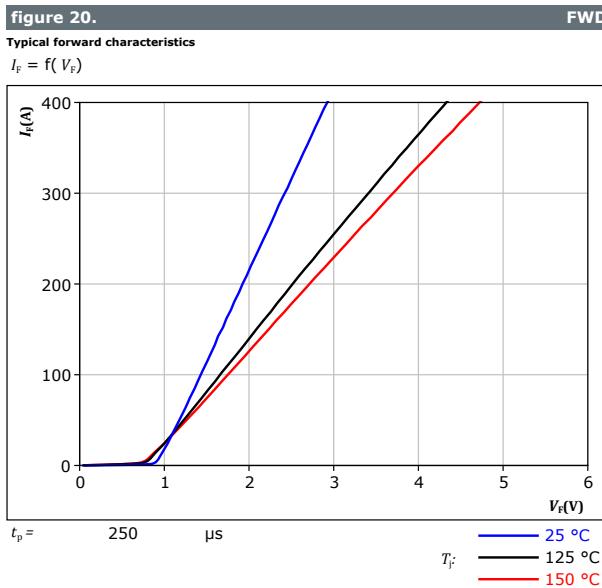




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Neutral Point Diode Characteristics





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datasheet

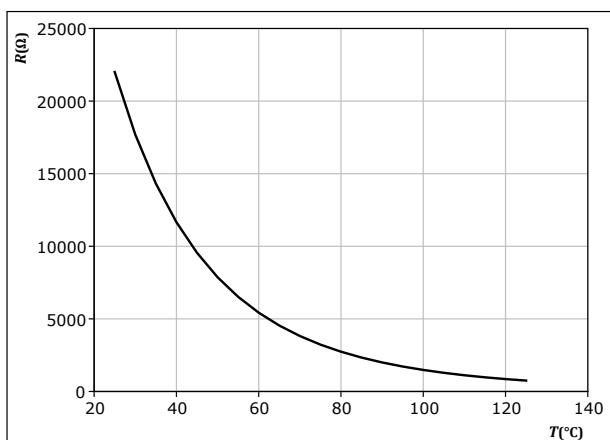
Thermistor Characteristics

figure 22.

Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





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datasheet

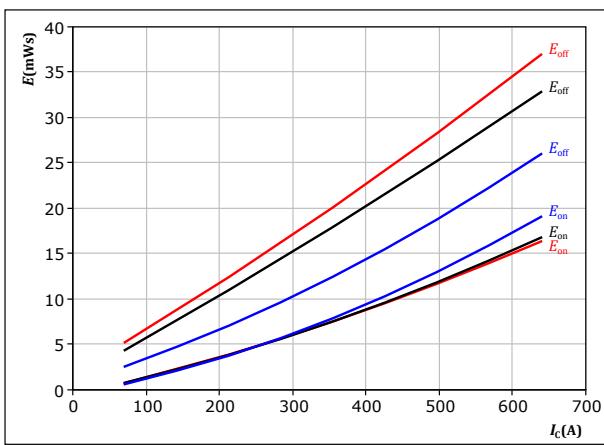
Neutral Point Switching Characteristics

figure 23.

Typical switching energy losses as a function of collector current

IGBT

$$E = f(I_c)$$



With an inductive load at

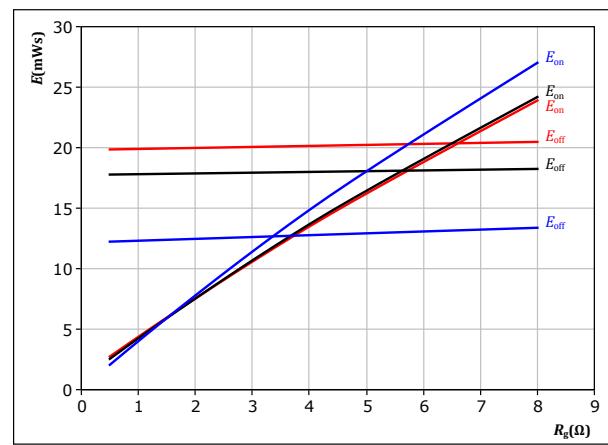
$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25^\circ\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ R_{gon} &= 2 \Omega & & \\ R_{goff} &= 2 \Omega & & \end{aligned}$$

figure 24.

IGBT

Typical switching energy losses as a function of IGBT turn on gate resistor

$$E = f(R_g)$$



With an inductive load at

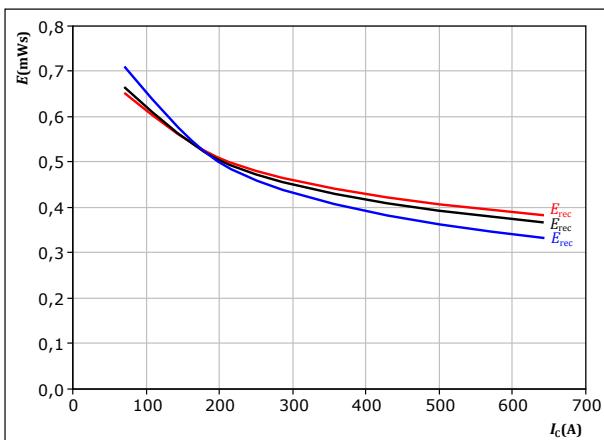
$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25^\circ\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ I_C &= 355 \text{ A} & & \\ & & & \text{---} \quad 125^\circ\text{C} \\ & & & \text{---} \quad 150^\circ\text{C} \end{aligned}$$

figure 25.

Typical reverse recovered energy loss as a function of collector current

FWD

$$E_{rec} = f(I_c)$$



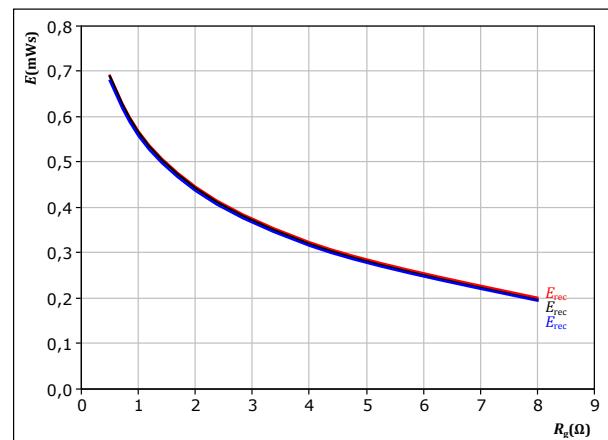
With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25^\circ\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ R_{gon} &= 2 \Omega & & \end{aligned}$$

figure 26.

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25^\circ\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ I_C &= 355 \text{ A} & & \\ & & & \text{---} \quad 125^\circ\text{C} \\ & & & \text{---} \quad 150^\circ\text{C} \end{aligned}$$



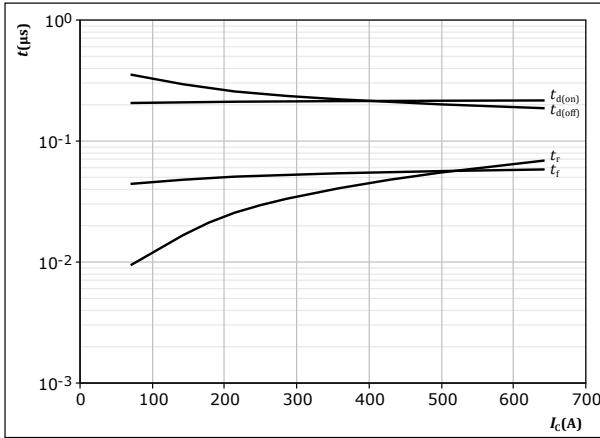
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datasheet

Neutral Point Switching Characteristics

figure 27. IGBT

Typical switching times as a function of collector current
 $t = f(I_C)$

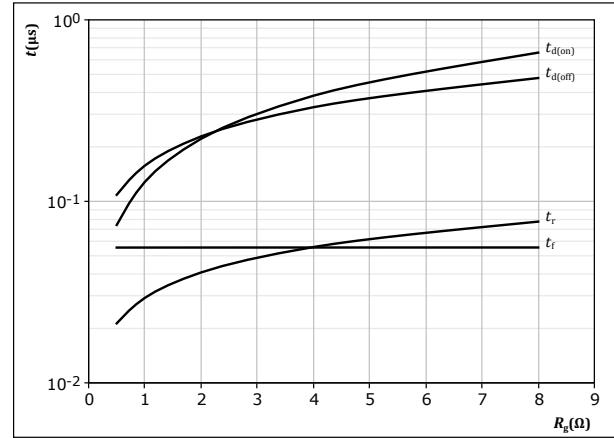


With an inductive load at

$T_j = 150 \text{ } ^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$
 $R_{goff} = 2 \Omega$

figure 28. IGBT

Typical switching times as a function of IGBT turn on gate resistor
 $t = f(R_g)$

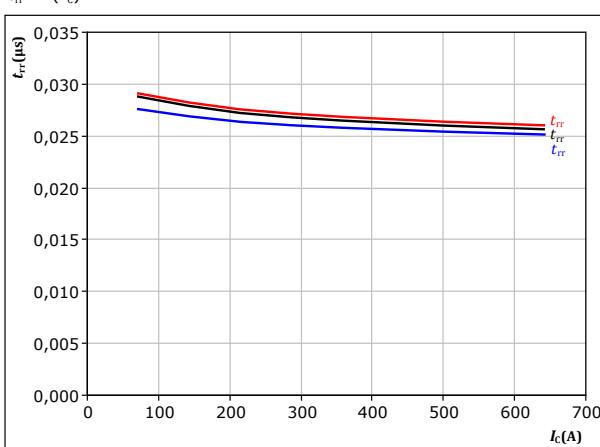


With an inductive load at

$T_j = 150 \text{ } ^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 355 \text{ A}$

figure 29. FWD

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$

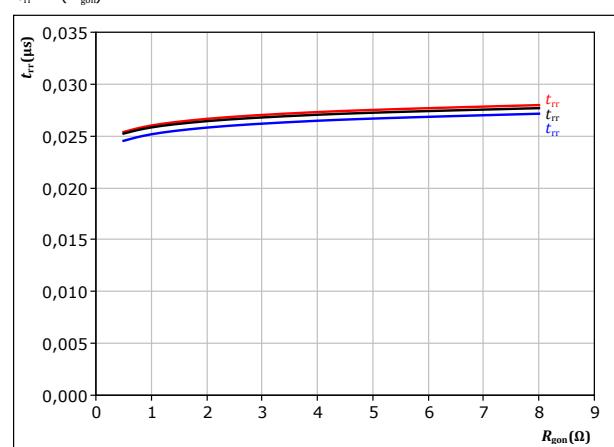


With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$

figure 30. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 355 \text{ A}$



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datasheet

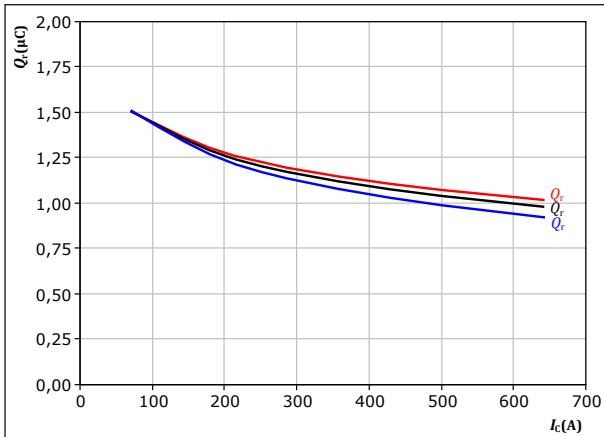
Neutral Point Switching Characteristics

figure 31.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

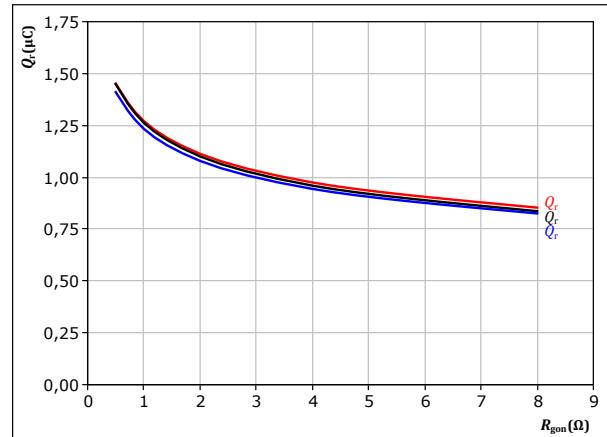
$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ R_{gon} &= 2 \Omega & & \\ & & & \end{aligned}$$

figure 32.

FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

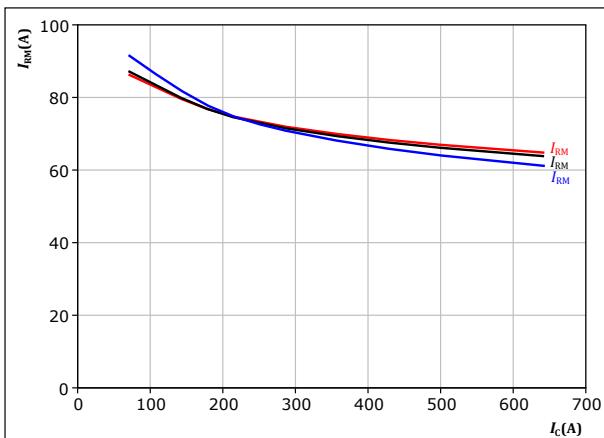
$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ I_c &= 355 \text{ A} & & \\ & & & \end{aligned}$$

figure 33.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

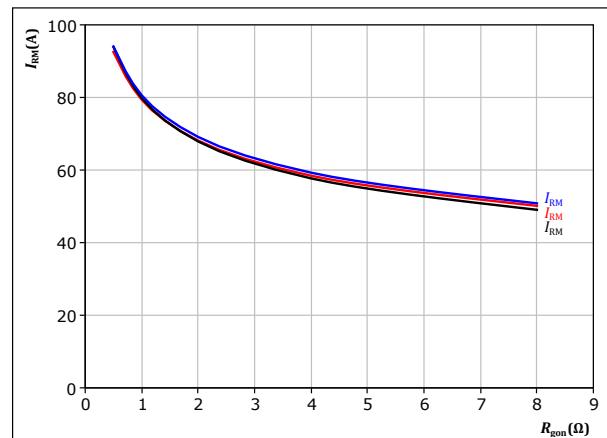
$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ R_{gon} &= 2 \Omega & & \\ & & & \end{aligned}$$

figure 34.

FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} & T_f &= 25 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ I_c &= 355 \text{ A} & & \\ & & & \end{aligned}$$



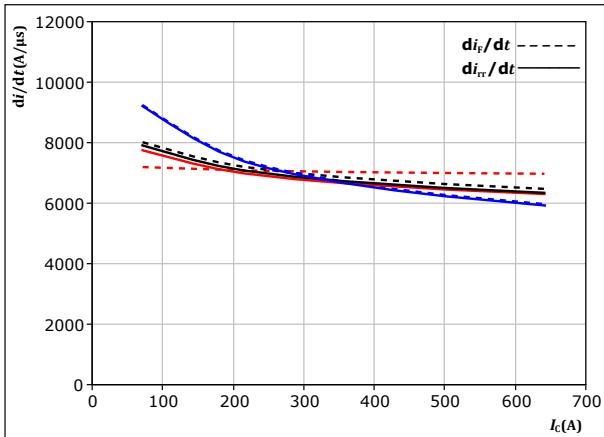
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Neutral Point Switching Characteristics

figure 35. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_{rr}/dt = f(I_c)$

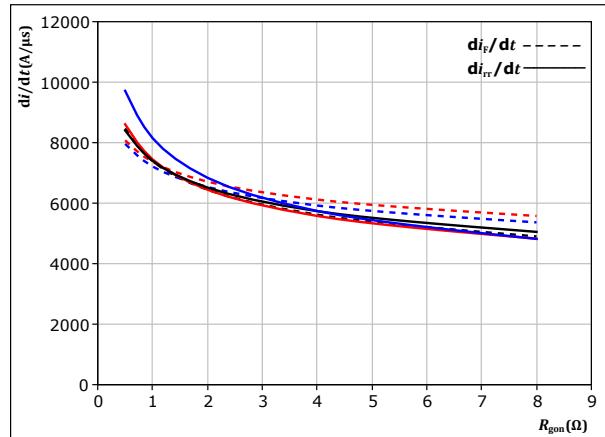


With an inductive load at

$V_{CE} = 600$ V	$T_j = 25$ °C
$V_{GE} = \pm 15$ V	$T_j = 125$ °C
$R_{gon} = 2$ Ω	$T_j = 150$ °C

figure 36. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



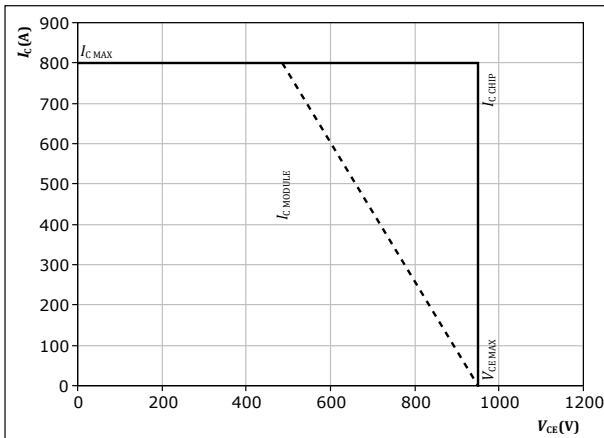
With an inductive load at

$V_{CE} = 600$ V	$T_j = 25$ °C
$V_{GE} = \pm 15$ V	$T_j = 125$ °C
$I_c = 355$ A	$T_j = 150$ °C

figure 37. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At $T_j = 150$ °C

$R_{gon} = 2$ Ω
$R_{goff} = 2$ Ω



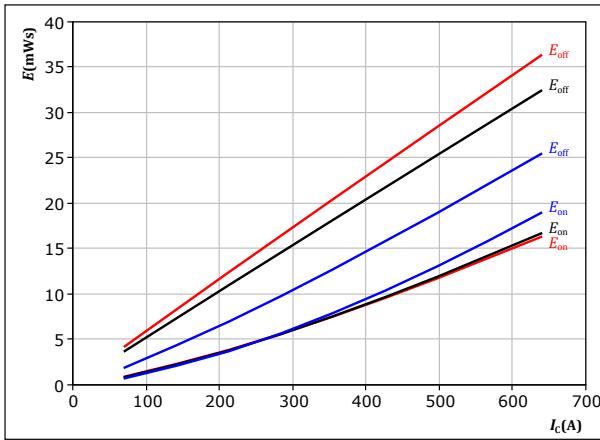
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DC-Link Switching Characteristics

figure 38.

Typical switching energy losses as a function of collector current
 $E = f(I_c)$



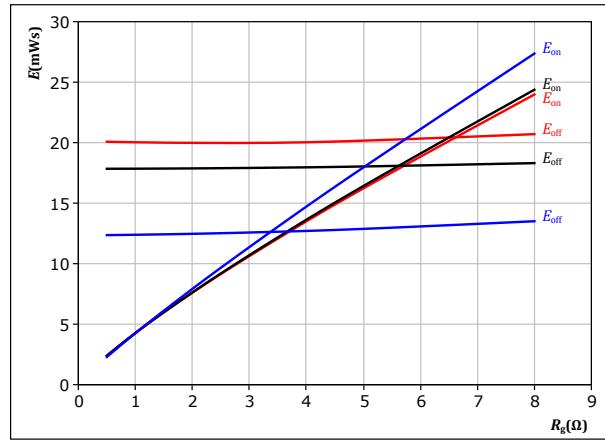
With an inductive load at

$V_{CE} = 600$ V $T_f = 25^\circ\text{C}$
 $V_{GE} = \pm 15$ V $T_f = 125^\circ\text{C}$
 $R_{gon} = 2$ Ω $T_f = 150^\circ\text{C}$
 $R_{goff} = 2$ Ω

IGBT

figure 39.

Typical switching energy losses as a function of IGBT turn on gate resistor
 $E = f(R_g)$



With an inductive load at

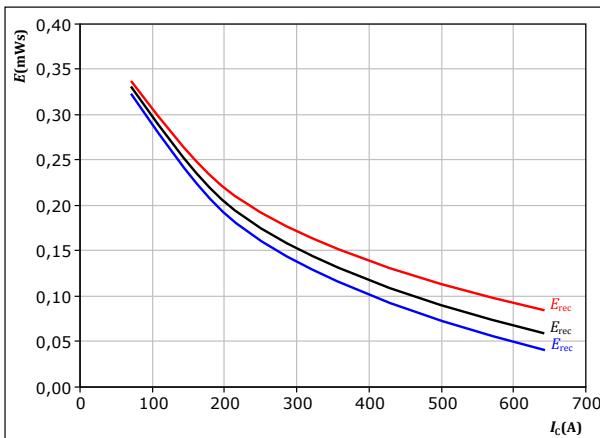
$V_{CE} = 600$ V $T_f = 25^\circ\text{C}$
 $V_{GE} = \pm 15$ V $T_f = 125^\circ\text{C}$
 $I_c = 355$ A $T_f = 150^\circ\text{C}$

IGBT

figure 40.

Typical reverse recovered energy loss as a function of collector current

$E_{rec} = f(I_c)$



With an inductive load at

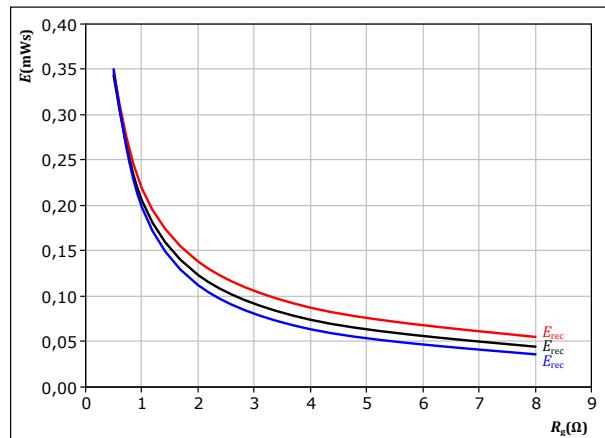
$V_{CE} = 600$ V $T_f = 25^\circ\text{C}$
 $V_{GE} = \pm 15$ V $T_f = 125^\circ\text{C}$
 $R_{gon} = 2$ Ω $T_f = 150^\circ\text{C}$

FWD

figure 41.

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$E_{rec} = f(R_g)$



With an inductive load at

$V_{CE} = 600$ V $T_f = 25^\circ\text{C}$
 $V_{GE} = \pm 15$ V $T_f = 125^\circ\text{C}$
 $I_c = 355$ A $T_f = 150^\circ\text{C}$

FWD



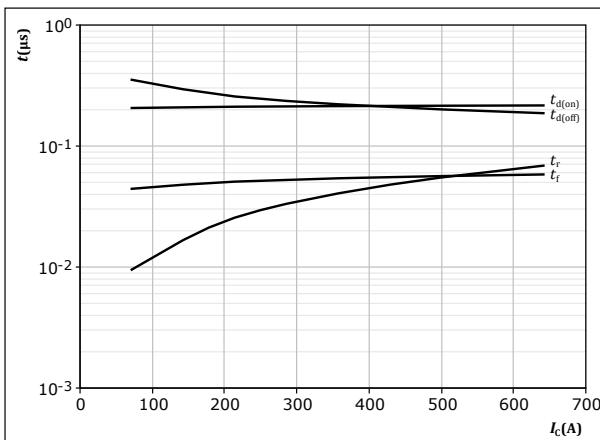
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datasheet

DC-Link Switching Characteristics

figure 42.

Typical switching times as a function of collector current
 $t = f(I_C)$



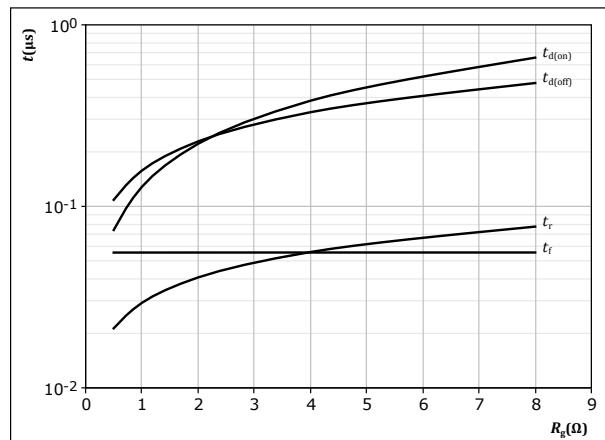
With an inductive load at

$T_j = 150 \text{ } ^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$
 $R_{goff} = 2 \Omega$

IGBT

figure 43.

Typical switching times as a function of IGBT turn on gate resistor
 $t = f(R_g)$



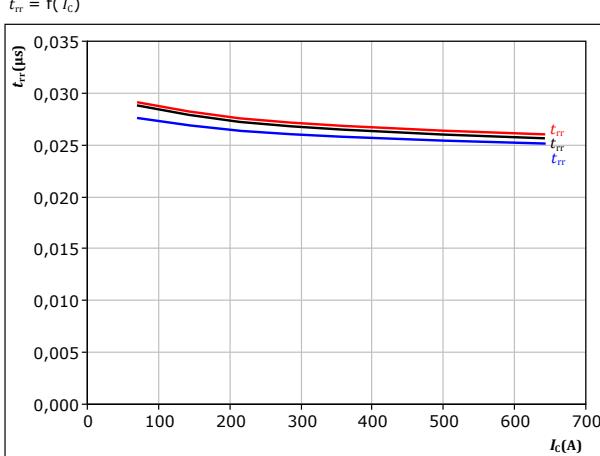
With an inductive load at

$T_j = 150 \text{ } ^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 355 \text{ A}$

IGBT

figure 44.

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$



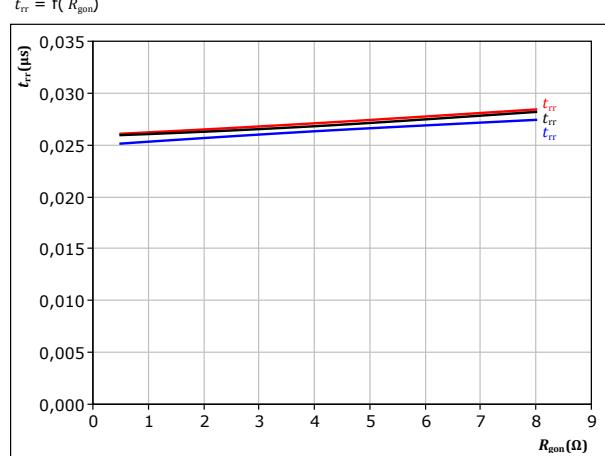
With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$

FWD

figure 45.

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 355 \text{ A}$

FWD



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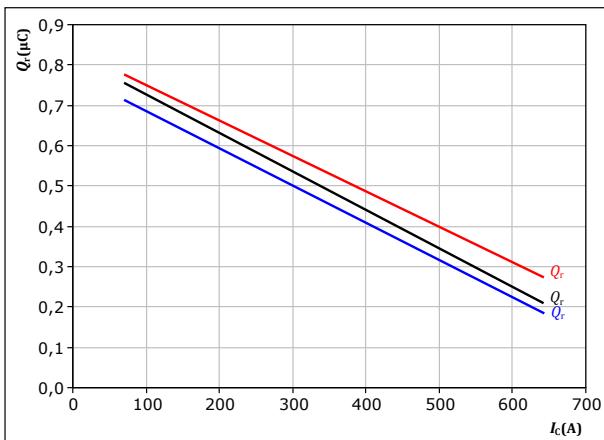
**BO-SP10NAD600S704-PE19F18T
BO-SP10NAE600S704-PE29F18T**
datasheet

DC-Link Switching Characteristics

figure 46.

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

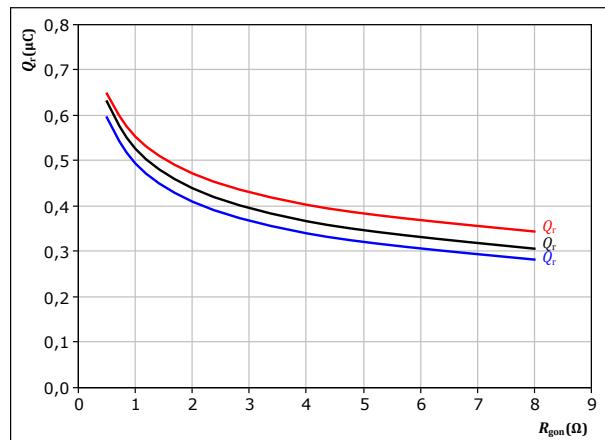
$$\begin{aligned} V_{CE} &= 600 \quad \text{V} & T_f &= 125 \quad ^\circ\text{C} \\ V_{GE} &= \pm 15 \quad \text{V} & & \\ R_{gon} &= 2 \quad \Omega & I_c &= 355 \quad \text{A} \end{aligned}$$

FWD

figure 47.

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$

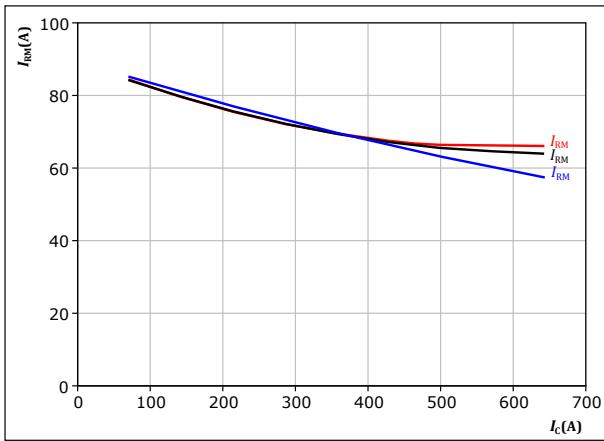


FWD

figure 48.

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

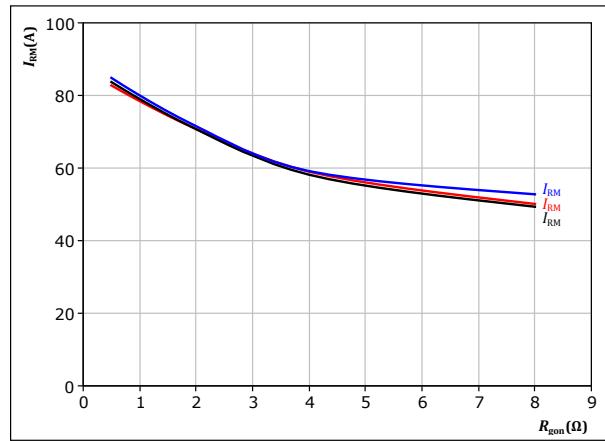
$$\begin{aligned} V_{CE} &= 600 \quad \text{V} & T_f &= 125 \quad ^\circ\text{C} \\ V_{GE} &= \pm 15 \quad \text{V} & & \\ R_{gon} &= 2 \quad \Omega & I_c &= 355 \quad \text{A} \end{aligned}$$

FWD

figure 49.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



FWD



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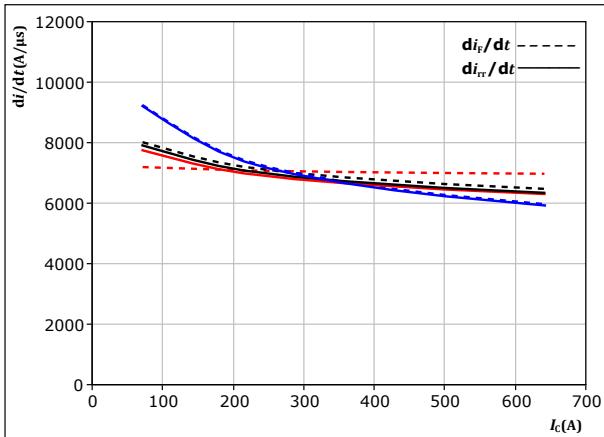
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BO-SP10NAE600S704-PE29F18T**
datasheet

DC-Link Switching Characteristics

figure 50.

FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_{rr}/dt = f(I_c)$



With an inductive load at

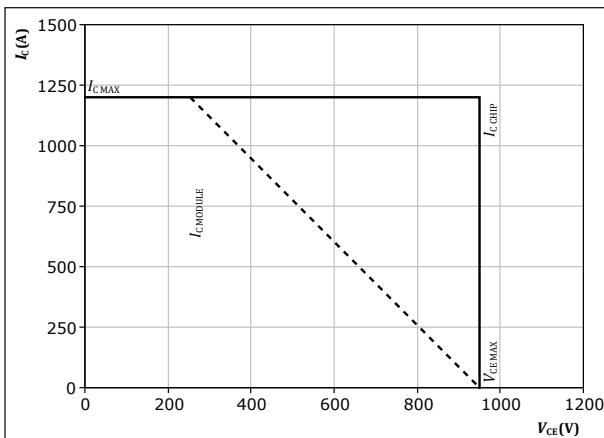
$V_{CE} = 600$ V	$T_j = 25^\circ\text{C}$
$V_{GE} = \pm 15$ V	$T_j = 125^\circ\text{C}$
$R_{gon} = 2$ Ω	$T_j = 150^\circ\text{C}$

figure 52.

IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



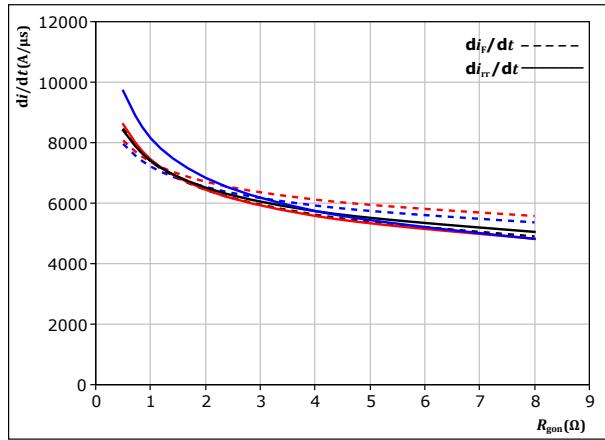
At $T_j = 150^\circ\text{C}$

$R_{gon} = 2$ Ω
$R_{goff} = 2$ Ω

figure 51.

FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

$V_{CE} = 600$ V	$T_j = 25^\circ\text{C}$
$V_{GE} = \pm 15$ V	$T_j = 125^\circ\text{C}$
$I_c = 355$ A	$T_j = 150^\circ\text{C}$



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datasheet

Switching Definitions

figure 53. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

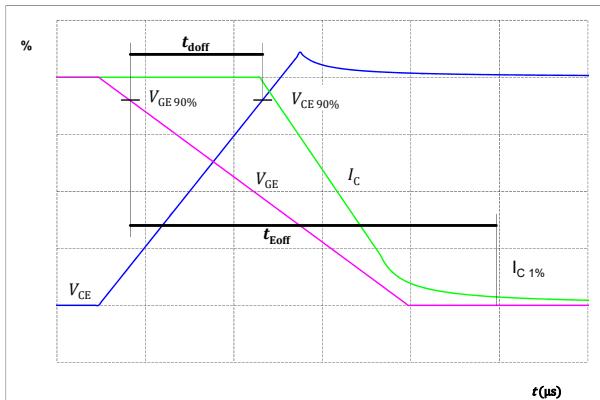


figure 55. IGBT

Turn-off Switching Waveforms & definition of t_f

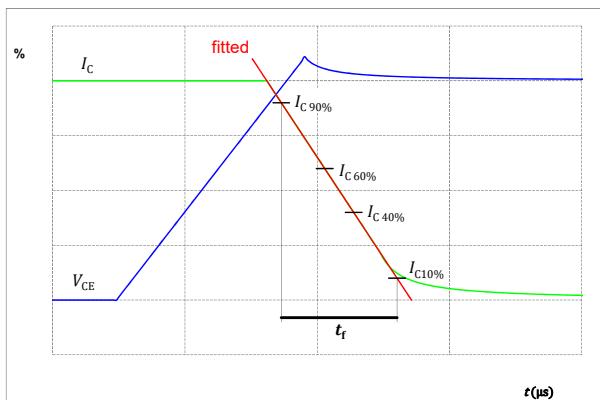


figure 54. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

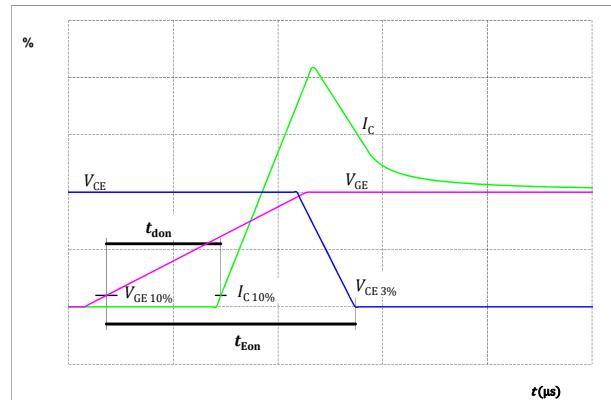
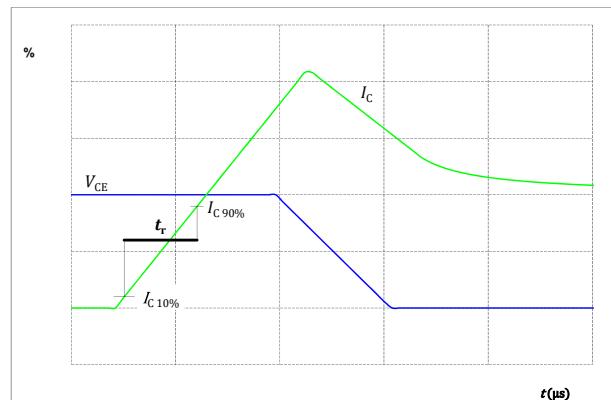


figure 56. IGBT

Turn-on Switching Waveforms & definition of t_r





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Switching Definitions

figure 57.

Turn-off Switching Waveforms & definition of t_{tr}

FWD

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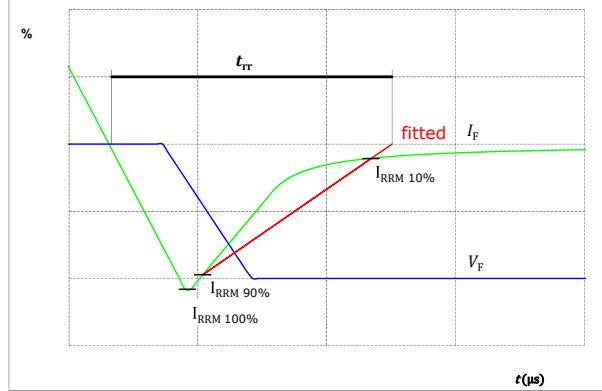
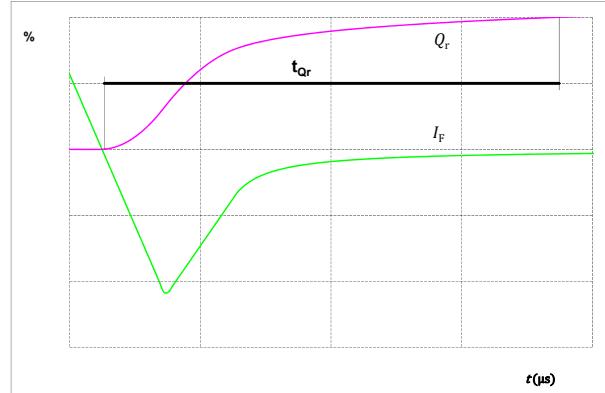


figure 58.

Turn-on Switching Waveforms & definition of t_{Qr} (t_{Qr} = integrating time for Q_r)

FWD

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**B0-SP10NAD600S704-PE19F18T
B0-SP10NAE600S704-PE29F18T**
datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	B0-SP10NAD600S704-PE19F18T
With thermal paste (5,2 W/mK, PTM6000HV)	B0-SP10NAD600S704-PE19F18T-/7/

Marking						
Text	Name	Date code	UL & VIN	Lot	Serial	
NNNNNNNNNNNNNN TTTTTTVVWWYY JL VIN LLLL SSSS	NN-NNNNNNNNNNNNNN- TTTTTTVV	WWYY	UL VIN	LLLLL	SSSS	
Datamatrix	Type&Ver	Lot number	Serial	Date code		
	TTTTTTVV	LLLLL	SSSS	WWYY		

High Side Module B0-SP10NAD600S704-PE19F18T

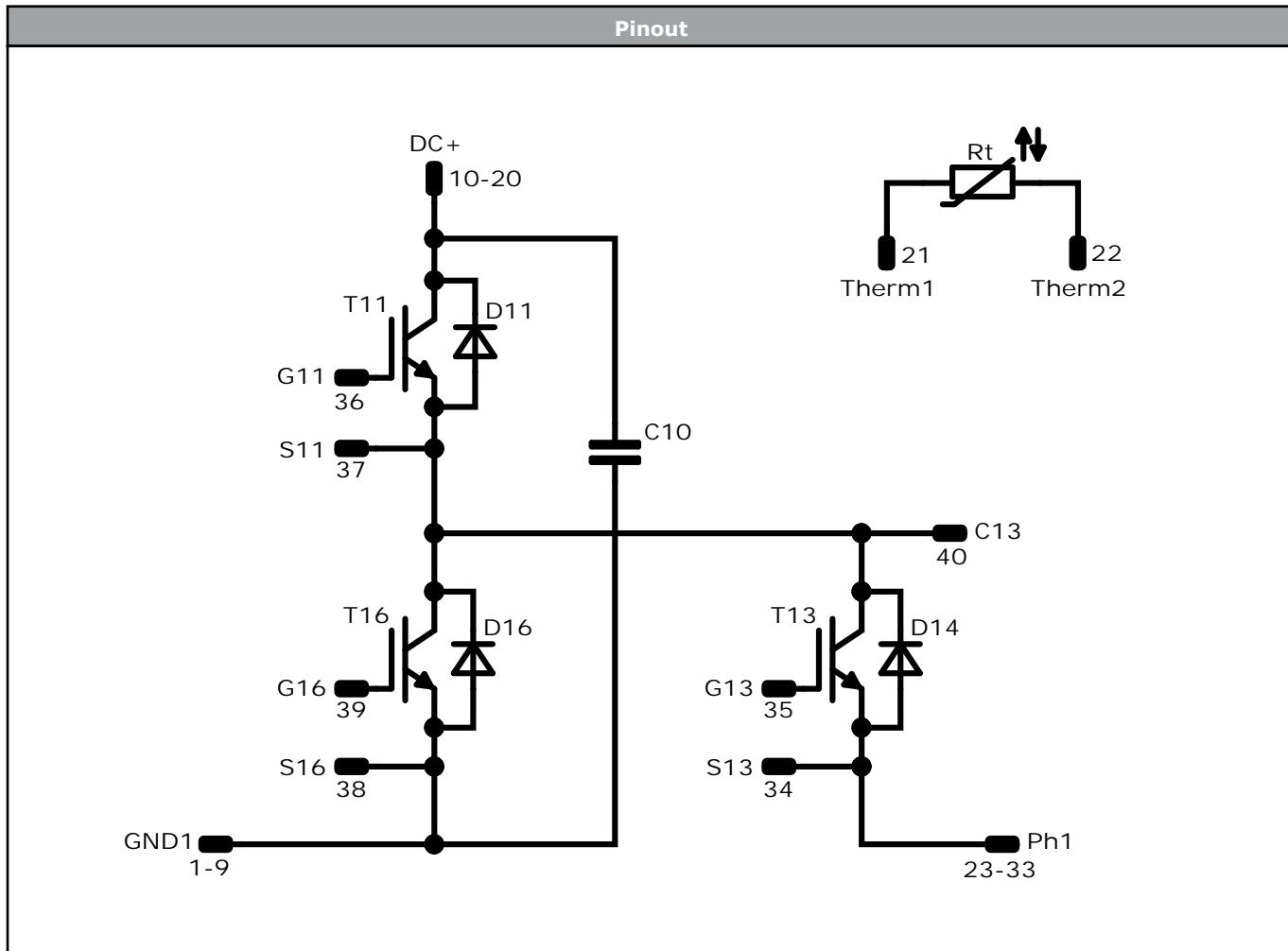
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Pin table [mm]				Dimensions [mm]																																																																																																																																																																						
<table border="1"> <thead> <tr> <th>Pin</th> <th>X</th> <th>Y</th> <th>Function</th> </tr> </thead> <tbody> <tr><td>1</td><td>52,4</td><td>2,7</td><td>GND1</td></tr> <tr><td>2</td><td>49,7</td><td>2,7</td><td>GND1</td></tr> <tr><td>3</td><td>52,4</td><td>0</td><td>GND1</td></tr> <tr><td>4</td><td>49,7</td><td>0</td><td>GND1</td></tr> <tr><td>5</td><td>47</td><td>0</td><td>GND1</td></tr> <tr><td>6</td><td>44,3</td><td>0</td><td>GND1</td></tr> <tr><td>7</td><td>41,6</td><td>0</td><td>GND1</td></tr> <tr><td>8</td><td>38,9</td><td>0</td><td>GND1</td></tr> <tr><td>9</td><td>36,2</td><td>0</td><td>GND1</td></tr> <tr><td>10</td><td>24,3</td><td>0</td><td>DC+</td></tr> <tr><td>11</td><td>21,6</td><td>0</td><td>DC+</td></tr> <tr><td>12</td><td>18,9</td><td>0</td><td>DC+</td></tr> <tr><td>13</td><td>16,2</td><td>0</td><td>DC+</td></tr> <tr><td>14</td><td>13,5</td><td>0</td><td>DC+</td></tr> <tr><td>15</td><td>10,8</td><td>0</td><td>DC+</td></tr> <tr><td>16</td><td>8,1</td><td>0</td><td>DC+</td></tr> <tr><td>17</td><td>5,4</td><td>0</td><td>DC+</td></tr> <tr><td>18</td><td>2,7</td><td>0</td><td>DC+</td></tr> <tr><td>19</td><td>0</td><td>0</td><td>DC+</td></tr> <tr><td>20</td><td>0</td><td>2,7</td><td>DC+</td></tr> <tr><td>21</td><td>0</td><td>43,4</td><td>Therm1</td></tr> <tr><td>22</td><td>0</td><td>50,4</td><td>Therm2</td></tr> <tr><td>23</td><td>25,4</td><td>50,4</td><td>Ph1</td></tr> <tr><td>24</td><td>28,1</td><td>50,4</td><td>Ph1</td></tr> <tr><td>25</td><td>30,8</td><td>50,4</td><td>Ph1</td></tr> <tr><td>26</td><td>33,5</td><td>50,4</td><td>Ph1</td></tr> <tr><td>27</td><td>36,2</td><td>50,4</td><td>Ph1</td></tr> <tr><td>28</td><td>38,9</td><td>50,4</td><td>Ph1</td></tr> <tr><td>29</td><td>41,6</td><td>50,4</td><td>Ph1</td></tr> <tr><td>30</td><td>44,3</td><td>50,4</td><td>Ph1</td></tr> <tr><td>31</td><td>47</td><td>50,4</td><td>Ph1</td></tr> <tr><td>32</td><td>49,7</td><td>50,4</td><td>Ph1</td></tr> <tr><td>33</td><td>52,4</td><td>50,4</td><td>Ph1</td></tr> <tr><td>34</td><td>36,4</td><td>47,7</td><td>S13</td></tr> <tr><td>35</td><td>39,9</td><td>46,45</td><td>G13</td></tr> <tr><td>36</td><td>18,65</td><td>12,25</td><td>G11</td></tr> <tr><td>37</td><td>21,65</td><td>12,25</td><td>S11</td></tr> <tr><td>38</td><td>49</td><td>20,4</td><td>S16</td></tr> <tr><td>39</td><td>46</td><td>20,4</td><td>G16</td></tr> <tr><td>40</td><td>24,95</td><td>34,9</td><td>C13</td></tr> </tbody> </table>	Pin	X	Y	Function	1	52,4	2,7	GND1	2	49,7	2,7	GND1	3	52,4	0	GND1	4	49,7	0	GND1	5	47	0	GND1	6	44,3	0	GND1	7	41,6	0	GND1	8	38,9	0	GND1	9	36,2	0	GND1	10	24,3	0	DC+	11	21,6	0	DC+	12	18,9	0	DC+	13	16,2	0	DC+	14	13,5	0	DC+	15	10,8	0	DC+	16	8,1	0	DC+	17	5,4	0	DC+	18	2,7	0	DC+	19	0	0	DC+	20	0	2,7	DC+	21	0	43,4	Therm1	22	0	50,4	Therm2	23	25,4	50,4	Ph1	24	28,1	50,4	Ph1	25	30,8	50,4	Ph1	26	33,5	50,4	Ph1	27	36,2	50,4	Ph1	28	38,9	50,4	Ph1	29	41,6	50,4	Ph1	30	44,3	50,4	Ph1	31	47	50,4	Ph1	32	49,7	50,4	Ph1	33	52,4	50,4	Ph1	34	36,4	47,7	S13	35	39,9	46,45	G13	36	18,65	12,25	G11	37	21,65	12,25	S11	38	49	20,4	S16	39	46	20,4	G16	40	24,95	34,9	C13	<p>center of package pin lead pin head type "T", PCB placed through-hole Φ min. 4,09 / -0,06 for further PCB design rules refer to the latest handling instruction</p>					
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				<p>Tolerance of plating areas: 0,05mm at the rest of pins Dimension of component size is only offset without tolerance.</p>																																																																																																																																																																						



BO-SP10NAD600S704-PE19F18T
BO-SP10NAE600S704-PE29F18T
datasheet

Vincotech

High Side Module BO-SP10NAD600S704-PE19F18T



Identification					
ID	Component	Voltage	Current	Function	Comment
T13	IGBT	950 V	400 A	AC Switch	
D14	FWD	950 V	300 A	AC Diode	
T16	IGBT	950 V	400 A	Neutral Point Switch	
D11	FWD	950 V	300 A	DC-Link Diode	
T11	IGBT	950 V	600 A	DC-Link Switch	
D16	FWD	1200 V	160 A	Neutral Point Diode	
C10	Capacitor	1000 V		Capacitor (DC)	
Rt	Thermistor			Thermistor	



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 datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	BO-SP10NAE600S704-PE29F18T
With thermal paste (5,2 W/mK, PTM6000HV)	BO-SP10NAE600S704-PE29F18T-/7/

Marking						
Text	Name	Date code	UL & VIN	Lot	Serial	
NNNNNNNNNNNNNN TTTTTTWWWWYJL VIN LLLL SSSS	NN-NNNNNNNNNNNNNN- TTTTTVV	WWYY	UL VIN	LLLLL	SSSS	
Datamatrix	Type&Ver	Lot number	Serial	Date code		
	TTTTTTVV	LLLLL	SSSS	WWYY		

Low Side Module BO-SP10NAE600S704-PE29F18T

Outline

Pin table [mm]			
Pin	X	Y	Function
1	52,4	2,7	DC-
2	52,4	0	DC-
3	49,7	0	DC-
4	47	0	DC-
5	44,3	0	DC-
6	41,6	0	DC-
7	38,9	0	DC-
8	36,2	0	DC-
9	33,5	0	DC-
10	30,8	0	DC-
11	28,1	0	DC-
12	16,2	0	GND2
13	13,5	0	GND2
14	10,8	0	GND2
15	8,1	0	GND2
16	5,4	0	GND2
17	2,7	0	GND2
18	0	0	GND2
19	2,7	2,7	GND2
20	0	2,7	GND2
21	0	50,4	Ph2
22	2,7	50,4	Ph2
23	5,4	50,4	Ph2
24	8,1	50,4	Ph2
25	10,8	50,4	Ph2
26	13,5	50,4	Ph2
27	16,2	50,4	Ph2
28	18,9	50,4	Ph2
29	21,6	50,4	Ph2
30	24,3	50,4	Ph2
31	27	50,4	Ph2
32	52,4	50,4	Therm1
33	52,4	43,4	Therm2
34	12,5	34,5	G14
35	16	33,2	S14
36	46	26,4	G12
37	49	26,4	S12
38	23,5	17,5	S15
39	20,5	17,5	G15
40	24,85	29,85	C12

center of press-fit pin head
pin head type "T" PCB plated through-hole Ø1mm ±0.09/-0.06
for further PCB design rules refer to the latest handling instruction

Tolerance of proportions: +0.04mm at the end of pins
Dimension or coordinate axis is only offset without tolerance

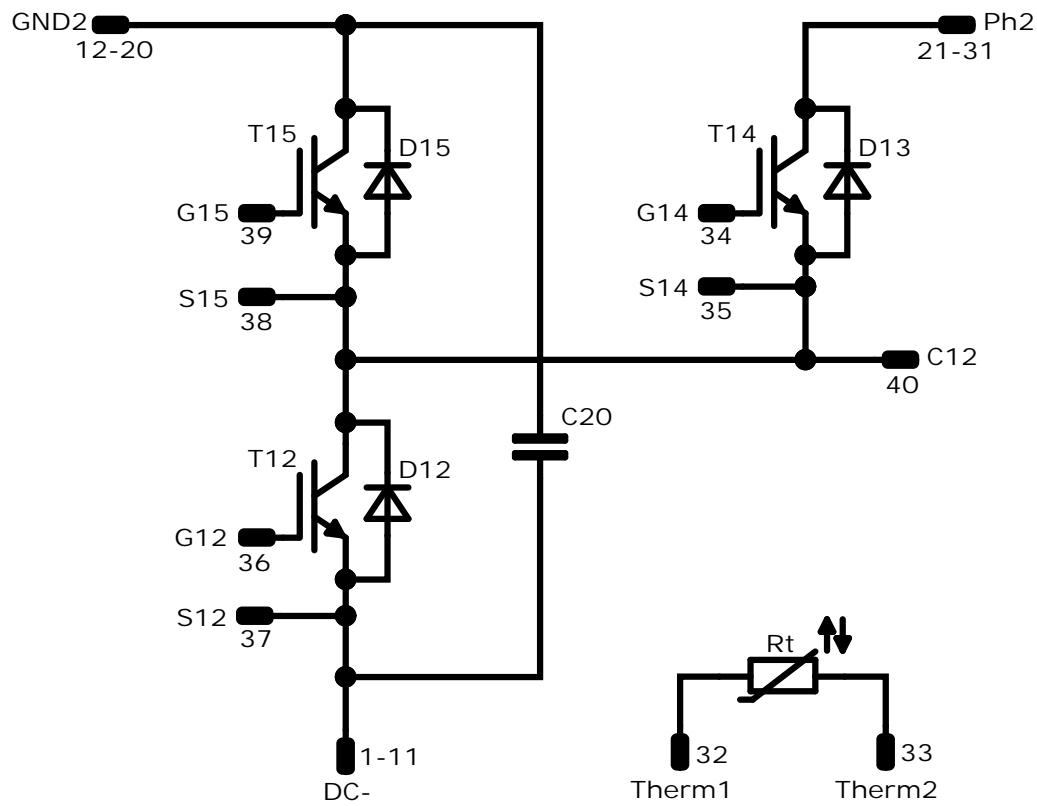


B0-SP10NAD600S704-PE19F18T
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Low Side Module B0-SP10NAE600S704-PE29F18T

Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T14	IGBT	950 V	400 A	AC Switch	
D13	FWD	950 V	300 A	AC Diode	
T15	IGBT	950 V	400 A	Neutral Point Switch	
D12	FWD	950 V	300 A	DC-Link Diode	
T12	IGBT	950 V	600 A	DC-Link Switch	
D15	FWD	1200 V	160 A	Neutral Point Diode	
C20	Capacitor	1000 V		Capacitor (DC)	
Rt	Thermistor			Thermistor	



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**B0-SP10NAD600S704-PE19F18T
B0-SP10NAE600S704-PE29F18T**
datasheet

Packaging instruction

Standard packaging quantity (SPQ) 45	>SPQ	Standard	<SPQ	Sample
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Handling instruction

Handling instructions for flow S3 packages see vincotech.com website.

Package data

Package data for flow S3 packages see vincotech.com website.

Vincotech thermistor reference

See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number

This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
B0-SP10NAx600S704-PEx9F18T-D3-14	23 Nov. 2022	New color of the frame: White	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.